

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : 7,737,012 B2  
APPLICATION NO. : 10/557746  
DATED : June 15, 2010  
INVENTOR(S) : Satoshi Shibata

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

ON THE TITLE PAGE:

In Item “(56) References Cited”, under “OTHER PUBLICATIONS” and  
before the Examiner Information, insert the following:

-- BORLAND “Low Temperature Activation of Ion

Implanted Dopants: A Review”, Japan Society of

Applied Physics, 202, pp. 85-88 --

Signed and Sealed this

Twelfth Day of October, 2010

A handwritten signature in black ink, reading "David J. Kappos". The signature is written in a cursive, flowing style with a large, stylized 'D' and 'K'.

David J. Kappos  
*Director of the United States Patent and Trademark Office*